





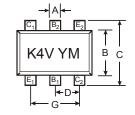
NPN DUAL SMALL SIGNAL SURFACE MOUNT TRANSISTOR

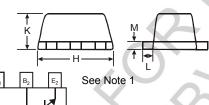
Features

- Epitaxial Die Construction
- Complementary PNP Type Available (BC857BV)
- Ultra-Small Surface Mount Package
- Lead Free By Design/RoHS Compliant (Note 3)
- "Green" Device (Note 5 and 6)

Mechanical Data

- Case: SOT-563
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin annealed over Alloy 42 leadframe. Solderable per MIL-STD-202, Method 208
- Marking Information: K4V, See Page 2
- Ordering & Date Code Information: See Page 2
- Weight: 0.003 grams (approximate)





SOT-563										
Dim	Min	Max	Тур							
Α	0.15	0.30	0.25							
В	1.10	1.25	1.20							
С	1.55	1.70	1.60							
D		1	0.50							
G	0.90	1.10	1.00							
н	1.50	1.70	1.60							
K	0.56	0.60	0.60							
L	0.10	0.30	0.20							
M	0.10	0.18	0.11							
All Dimensions in mm										

Maximum Ratings @TA = 25°C unless otherwise specified

Characteristic		Symbol	Value	Unit	
Collector-Base Voltage	1	V_{CBO}	50	V	
Collector-Emitter Voltage		V _{CEO}	45	V	
Emitter-Base Voltage		V_{EBO}	6.0	V	
Collector Current		Ic	100	mA	
Power Dissipation	(Note 2)	P_d	150	mW	
Thermal Resistance, Junction to Ambient	(Note 2)	$R_{ heta JA}$	833	°C/W	
Operating and Storage Temperature Range		T _j , T _{STG}	-55 to +150	°C	

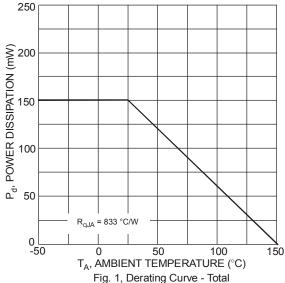
Electrical Characteristics @TA = 25°C unless otherwise specified

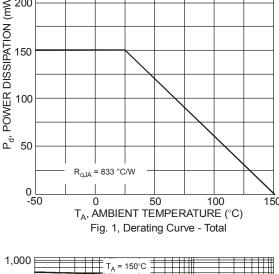
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
Collector-Base Breakdown Voltage	(Note 4)	V _{(BR)CBO}	50	_	_	V	$I_C = 10 \mu A, I_B = 0$
Collector-Emitter Breakdown Voltage	(Note 4)	V _{(BR)CEO}	45	_	-	V	$I_C = 10 \text{mA}, I_B = 0$
Emitter-Base Breakdown Voltage	(Note 4)	V _{(BR)EBO}	6	_	1	V	$I_E = 1\mu A, I_C = 0$
DC Current Gain	(Note 4)	h _{FE}	200	290	450	_	$V_{CE} = 5.0V, I_{C} = 2.0mA$
Collector-Emitter Saturation Voltage	(Note 4)	$V_{\text{CE}(\text{SAT})}$	_	_	100 300	mV	I_C = 10mA, I_B = 0.5mA I_C = 100mA, I_B = 5.0mA
Base-Emitter Saturation Voltage	(Note 4)	V _{BE(SAT)}	_	700 900	1	mV	I_C = 10mA, I_B = 0.5mA I_C = 100mA, I_B = 5.0mA
Base-Emitter Voltage	(Note 4)	V_{BE}	580 —	660 —	700 770	mV	$V_{CE} = 5.0V, I_{C} = 2.0mA$ $V_{CE} = 5.0V, I_{C} = 10mA$
Collector-Emitter Cutoff Current	(Note 4)	I _{CBO}	_	_	15 5.0	nΑ μΑ	V _{CB} = 30V V _{CB} = 30V, T _A = 150°C
Gain Bandwidth Product		f _T	100	_	ı	MHz	V _{CE} = 5.0V, I _C = 10mA, f = 100MHz
Output Capacitance		C _{OBO}	_	_	4.5	pF	V _{CB} = 10V, f = 1.0MHz
Noise Figure		NF	_	_	10	dB	V_{CE} = 5V, R _S = 2.0kΩ, f = 1.0kHz, BW = 200Hz

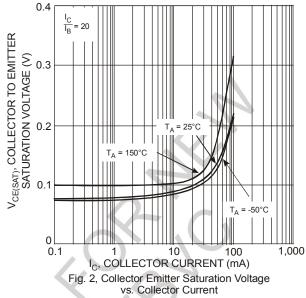
Notes:

- 1. Package is non-polarized. Parts may be on reel in orientation illustrated, 180° rotated, or mixed (both ways).
- 2. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
- 3. No purposefully added lead.
- No purposerully added lead.
 Short duration pulse test used to minimize self-heating effect.
- 5. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
- 6. Product manufactured with Date Code UO (week 40, 2007) and newer are built with Green Molding Compound. Product manufactured prior to Date Code UO are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.









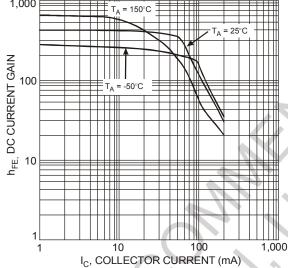


Fig. 3, DC Current Gain vs. Collector Current

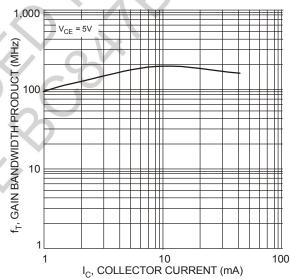


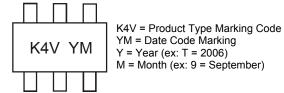
Fig. 4, Gain Bandwidth Product vs. Collector Current

Ordering Information (Note 7)

Device	Packaging	Shipping		
BC847BV-7	SOT-563	3000/Tape & Reel		

7. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



Date Code Key

<u> </u>												
Year	2003	2004	20	05	2006	2007	2008	2009	20	10	2011	2012
Code	Р	R	•	S	T	U	V	W		X	Υ	Z
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



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